

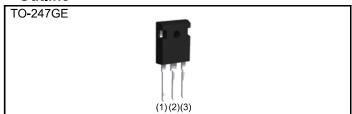
RGE80TS65DGC13

650V 40A Field Stop Trench IGBT

Datasheet

V _{CES}	650V
I _C	40A
V _{CE(sat) (Typ.)}	1.65V
P_{D}	200W

●Outline



Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Low Switching Loss
- 3) Short Circuit Withstand Time 5µs
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating; RoHS Compliant

Application

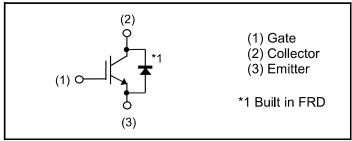
General Inverter

UPS

Power Conditioner

Welder

●Inner Circuit



Packaging Specifications

Type	Packaging	Tube				
	Reel Size (mm)	-				
	Tape Width (mm)	-				
	Basic Ordering Unit (pcs)	600				
	Packing Code	C13				
	Marking	RGE80TS65D				

● **Absolute Maximum Ratings** (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		$V_{\sf CES}$	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	63	Α
Collector Current	T _C = 100°C	I _C	40	Α
Pulsed Collector Current		I _{CP} *1	120	Α
Diode Forward Current	T _C = 25°C	I _F	52	Α
	T _C = 100°C	I _F	31	Α
Diode Pulsed Forward Current		I _{FP} *1	120	Α
Pawer Dissination	T _C = 25°C	P _D	200	W
Power Dissipation	T _C = 100°C	P _D	100	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.75	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	1	-	1.26	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	ı	ı	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$	ı	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 10.7 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation	W	$I_C = 40A, V_{GE} = 15V,$		4.05	2.05	
Voltage	$V_{CE(sat)}$	T _j = 25°C T _j = 175°C		1.65 2.15	2.05 -	V

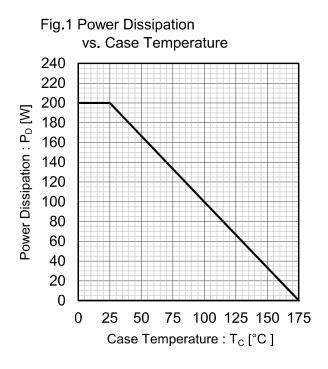
●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Doromotor	Cymahal	Conditions	Values			l loit
Parameter	neter Symbol Conditions	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V,	-	2464	-	
Output Capacitance	C _{oes}	V _{GE} = 0V,	-	107	-	рF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	26	-	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	85	-	
Gate - Emitter Charge	Q_ge	I _C = 40A,	-	19	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	38	-	
Turn - on Delay Time	t _{d(on)}		-	49	-	
Rise Time	t _r	$I_C = 40A, V_{CC} = 400V,$ $V_{GE} = 15V, R_G = 10\Omega,$	-	19	-	no
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	131	-	ns
Fall Time	t _f	Inductive Load *E _{on} include diode reverse recovery	-	77	-	
Turn-on Switching Loss	E _{on}		-	1.09	-	- mJ
Turn-off Switching Loss	E _{off}		-	0.78	-	
Turn - on Delay Time	t _{d(on)}		-	50	-	
Rise Time	t _r	$I_C = 40A, V_{CC} = 400V, V_{GF} = 15V, R_G = 10\Omega,$	-	22	-	no
Turn - off Delay Time	$t_{d(off)}$	T _j = 175°C Inductive Load	-	148	-	ns
Fall Time	t _f		-	88	-	
Turn-on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	1.17	-	mJ
Turn-off Switching Loss	E _{off}	1000100100001	-	1.02	-	IIIJ
		$I_C = 120A, V_{CC} = 520V,$	FULL SQUARE -			
Reverse Bias Safe Operating Area	RBSOA	$V_p = 650V, V_{GE} = 15V,$			-	
		$R_G = 100\Omega, T_j = 175^{\circ}C$				
Short Circuit Withstand Time	t _{sc}	$V_{CC} \le 360V,$ $V_{GE} = 15V, T_j = 25^{\circ}C$	5	-	-	μs

•FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Diode Forward Voltage	V _F	I _F = 40A, T _j = 25°C T _i = 175°C	- -	1.6 1.65	2.05 -	V
Diode Reverse Recovery Time	t _{rr}	,	-	183	-	ns
Diode Peak Reverse Recovery Current	Im	$I_F = 40A$, $V_{CC} = 400V$, $di_F/dt = 500A/\mu s$, $T_j = 25^{\circ}C$	-	12.6	-	А
Diode Reverse Recovery Charge	Q _{rr}		-	1.1	-	μC
Diode Reverse Recovery Energy	E _{rr}		-	227	-	μJ
Diode Reverse Recovery Time	t _{rr}	$I_F = 40A,$ $V_{CC} = 400V,$ $di_F/dt = 500A/\mu s,$ $T_j = 175^{\circ}C$	-	235	-	ns
Diode Peak Reverse Recovery Current	I _{rr}		-	16.5	-	Α
Diode Reverse Recovery Charge	Q _{rr}		_	2.2	_	μC
Diode Reverse Recovery Energy	E _{rr}		-	230	-	μJ

● Electrical Characteristic Curves



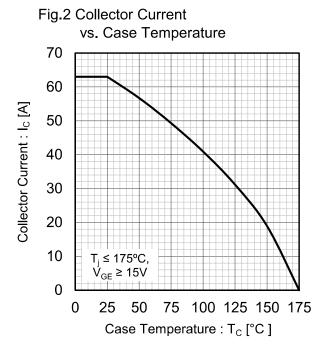
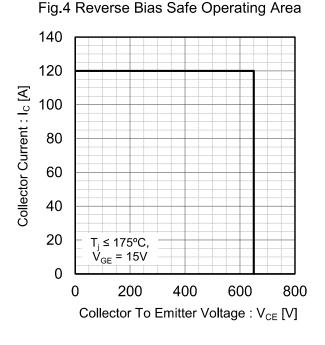


Fig.3 Forward Bias Safe Operating Area 1000 10µs 100 Collector Current : Ic [A] 100µs 10 1 0.1 $T_{\rm C} = 25^{\circ}{\rm C}$ Single Pulse 0.01 10 100 1000 Collector To Emitter Voltage: V_{CE} [V]



Collector To Emitter Saturation

● Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

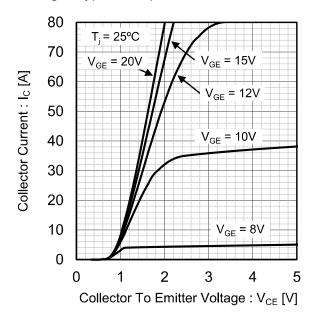


Fig.6 Typical Output Characteristics

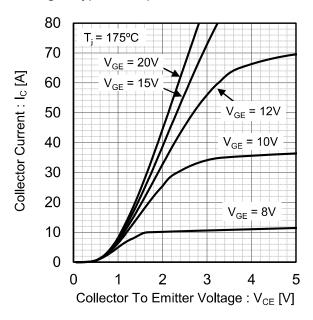


Fig.7 Typical Transfer Characteristics

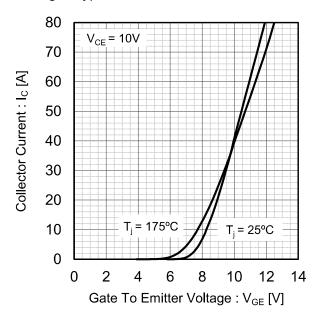
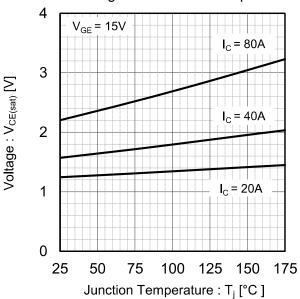


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



● Electrical Characteristic Curves

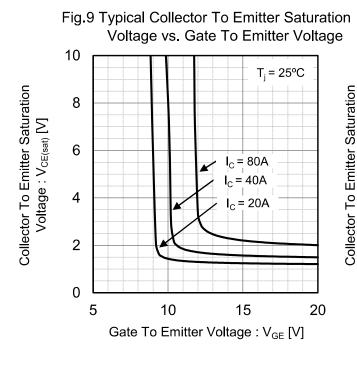
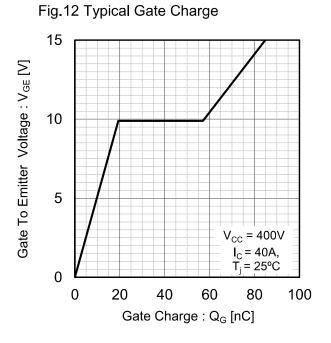


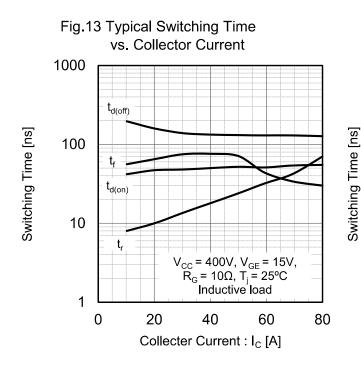
Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage 10 T_i = 175°C 8 Voltage: V_{CE(sat)} [V] $I_{\rm C} = 80A$ 6 $I_{\rm C} = 40A$ $I_{\rm C} = 20A$ 4 2 0 5 10 15 20

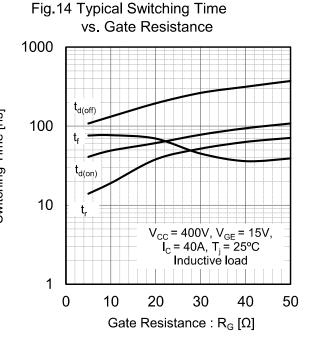
Gate To Emitter Voltage : $V_{GE}[V]$

Fig.11 Typical Capacitance vs. Collector To Emitter Voltage 100000 10000 Capacitance [pF] 1000 C_{oes} 100 10 f = 1MHz $V_{GE} = 0V$ C_{res} = 25°C 0.01 1 10 100 0.1 Collector To Emitter Voltage: V_{CE} [V]



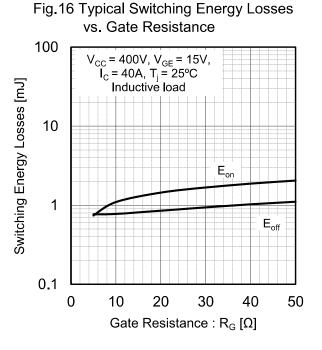
Electrical Characteristic Curves



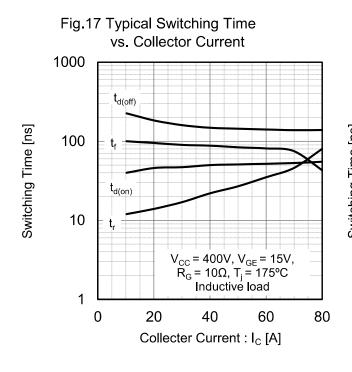


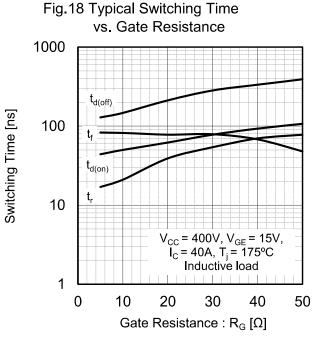
vs. Collector Current 100 $V_{CC} = 400V, V_{GE} = 15V,$ $R_{G} = 10\Omega, T_{j} = 25^{\circ}C$ Switching Energy Losses [mJ] Inductive load 10 E_{on} 1 E_{off} 0.1 20 40 60 0 80 Collecter Current : I_C [A]

Fig.15 Typical Switching Energy Losses



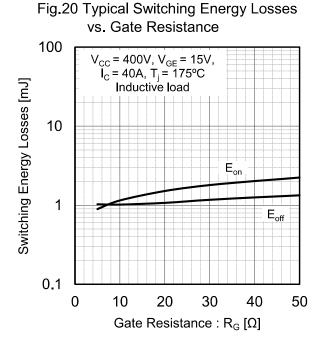
Electrical Characteristic Curves





vs. Collector Current 100 $V_{CC} = 400V, V_{GE} = 15V,$ $R_G = 10\Omega, T_j = 175^{\circ}C$ Switching Energy Losses [mJ] Inductive load 10 E_{on} $\mathsf{E}_{\mathsf{off}}$ 1 0.1 20 40 60 0 80 Collecter Current : I_C [A]

Fig.19 Typical Switching Energy Losses



● Electrical Characteristic Curves

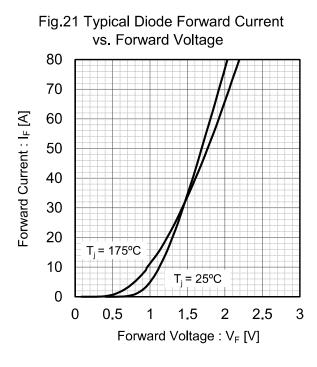
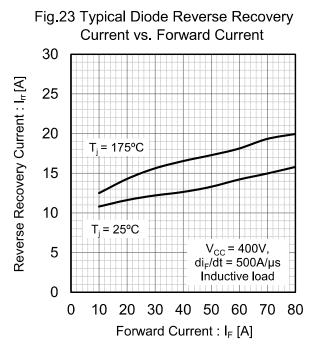


Fig. 22 Typical Diode Reverce Recovery Time vs. Forward Current

400 $T_j = 175^{\circ}C$ $T_j = 175^{\circ}C$ $T_j = 25^{\circ}C$ $T_j = 25^{\circ}C$



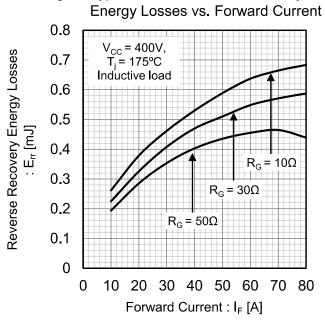


Fig.24 Typical Diode Reverse Recovery

● Electrical Characteristic Curves



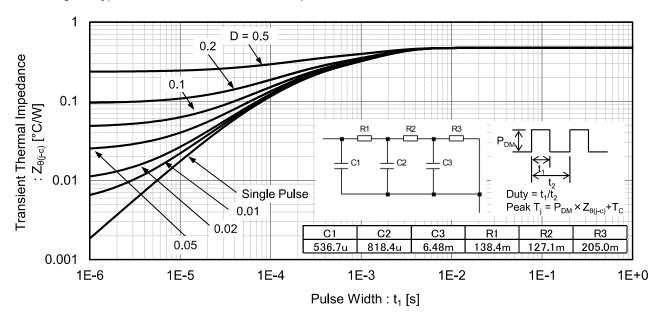
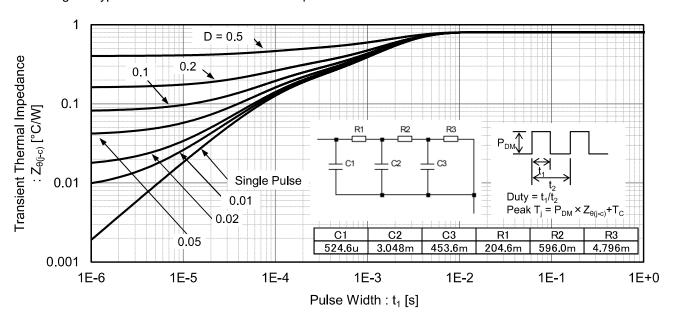


Fig.26 Typical Diode Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform and Short Circuit

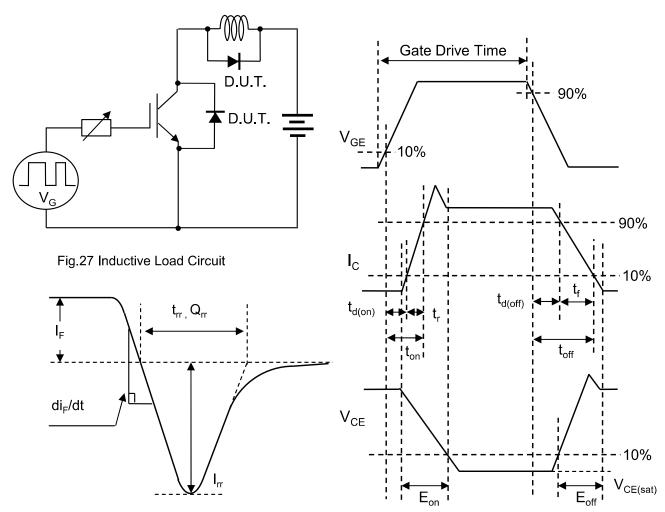


Fig.28 Diode Reverse Recovery Waveform

Fig.29 Inductive Load Waveform

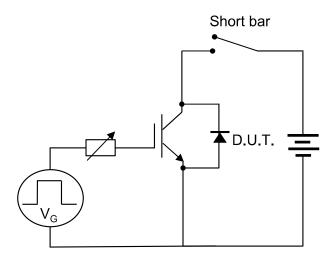


Fig.30 Short Circuit

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